Application No.: 10/570,151

Art Unit: 1795

Amendment under 37 CFR §1.116

Attorney Docket No.: 071850

.. 1793 Attorney Docket No.: 0718

**REMARKS** 

Claims 1 and 3-17 are pending. Claim 1 is amended herein. Support for the amendments

is detailed below.

Applicants' Response to the Claim Rejections under 35 U.S.C. §112

Claims 1 and 3-17 are rejected under 35 U.S.C. §112, second paragraph, as being

indefinite for failing to particularly point out and distinctly claim the subject matter.

Specifically, in the amendment reference to the Dv50/Dv10 ratio being 1.8 or more was

not properly removed. Applicants have removed the reference to the ratio by amendment to

claim 1 herein. Wherefore, applicants respectfully submit that claim 1 and its respective

dependents are now definite.

Applicants' Response to the Claim Rejections under 35 U.S.C. §103

Claims 1, 3, 6-8 and 10-16 are rejected under 35 U.S.C. §103(a) as being

unpatentable over Takiguchi et al. (US 2004/0043315) in view of JP '423 (JP 2002-182423).

In response thereto, applicants respectfully submit that the combination of references does

not render the invention as now claimed obvious for at least the reason that the combination does

not disclose all the features of the invention as claimed, nor is there any prompting from the

references or within the knowledge of the art which would lead a skilled artisan to derive the

current invention.

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Specifically, the combination of references at least fails to provide for the feature of claim

1 which states that the silica fine particle (A) is nonconductive.

The rejection relies upon the disclosures in Takiguchi of the conductive inorganic

metallic-compound fine particles as being equivalent to the silica fine particles of the claims. As

described at paragraph [0070], the metallic-compound fine particle may comprise a silicon oxide.

Further, the rejection admits that the sphericity range is not disclosed by Takiguchi, and relies

upon the previously cited disclosures of JP' 423 for this element. JP'423 is not otherwise relied

upon, nor does it contain any teaching regarding the features for which Takaiguchi is relied upon

by the rejection.

Takiguchi is teaching the metallic-compound fine particles as having a Dv50/Dv10 ratio

of 2 or more; whereas, the present invention is utilizing a silica inorganic fine powder having this

ratio. Specifically, according to one possible embodiment of the present invention, as described

in applicants' specification from pages 7-13, the toner includes an external additive comprising:

(1) silica fine particle (A) which has the characteristics set forth in claim 1; (2) possibly silica

particle (B) which has a smaller volume average particle diameter in the range of 5 to 80nm; and,

(3) a conductive organic fine particle which may be a silicon oxide fine particle surface-treated

with tin oxide doped antimony (see pg.12, l. 26 to pg.13, l. 2). Contrary, Takiguchi teaches the

metallic-compound fine particle as having the Dv50/Dv10 ratio, and a silica inorganic fine

particle with an average particle size of 4 to 80nm (see ¶[0078]). As such, the particles having

the Dv50/Dv10 ratio in Takiguchi must be the conductive inorganic compounds. As set forth in

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Table 1 of Takiguchi, all of the particles have a significant tin oxide weight percentage (wt. %)

with the exception of compound no. 18 which utilizes zinc oxide (see [0287]).

Applicant's claim 1, as now presented distinguishing that the claimed silica particle is not

a conductive inorganic metallic-compound fine particle. This property is inherent to the particle.

In order to prove this, the Applicant submits the attached reference material. The reference

material describes that the resistivity of silica fine particles is  $1 \times 10^{13} \Omega m$  (=  $1 \times 10^{15} \Omega cm$ ). From

this description, it is evident that silica is inherently nonconductive.

However, as noted above, the particle of Takiguchi must be conductive. JP '423 likewise

does not disclose this feature of the present invention. As such, the combination of references

does not provide for all the features of the presently claimed invention. Further, there is no

reason whereby a skilled artisan would derive this feature based on the combination of

references. As noted in M.P.E.P. §2143.01, under U.S. patent law a proposed modification

cannot render the prior art unsatisfactory for its intended purpose. Such a modification would be

necessary in order for the prior art to reach the present invention. Specifically, a skilled artisan

would not convert the conductive material of Takiguchi to a non-conductive material, as the

conductivity of the particles within Takiguchi is necessary for the invention thereof to function.

Wherefore, applicants respectfully submit that claim 1 as now presented and its respective

dependent claims are not obvious in light of the combination of Takiguchi and JP '423.

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Claims 4 and 5 are rejected under 35 U.S.C. §103(a) as being unpatentable over

Takiguchi et al. in view of JP '423 as applied above, and further in view of JP '450 (JP

2003-029450).

Claim 8 is rejected under 35 U.S.C. §103(a) as being unpatentable over Takiguchi et

al. in view of JP '423 as applied above, and further in view of Hagi et al. (US 5,776,646).

Claim 17 is rejected under 35 U.S.C. §103(a) as being unpatentable over Takiguchi

et al. in view of JP '423 as applied above, and further in view of Niwa (US 2003/0027070).

As these rejections all depend from the rejection of claim 1, by addressing the rejection of

claim 1 as detailed above, likewise these rejections should be considered addressed by nature of

their dependency.

In view of the aforementioned amendments and accompanying remarks, Applicants

submit that the claims, as herein amended, are in condition for allowance. Applicants request

such action at an early date.

If the Examiner believes that this application is not now in condition for allowance, the

Examiner is requested to contact Applicants' undersigned attorney to arrange for an interview to

expedite the disposition of this case.

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If this paper is not timely filed, Applicants respectfully petition for an appropriate extension of time. The fees for such an extension or any other fees that may be due with respect to this paper may be charged to Deposit Account No. 50-2866.

Respectfully submitted,

WESTERMAN, HATTORI, DANIELS & ADRIAN, LLP

Michael J. Caridi Attorney for Applicants Registration No. 56,171

Telephone: (202) 822-1100 Facsimile: (202) 822-1111

MJC/tw

Enclosures: Reference w/ partial translation

## Partial translation of the reference

		Compound	crystal	resistivity	temperature	
			structure	10 Ωm	θ /°C	
5	Oxides	SiO2	hexagonal	1×10 <sup>21</sup>	20	

	AN ARIXA HIMPONIMINATOR A CANTE	ACCUMENT .	- <del> </del>	SP (SEPROM)	
<b>会 盘</b>	組 成(質量%)	温 LE 6/℃	抵抗率 p/10 <sup>-1</sup> Qm	抵抗率の編度係数 a/10 <sup>-3</sup> K <sup>-1</sup>	
カンタル	Cr (22-25), Al (5.0-5.5), Co (1.6-3.0), 残事。	20	1.45	0.06	
ケイ景鋼	Si(4.6),残Fe	室協	0.625	0,75	
コンスタンタン	Cu (60), Ni (40)	宜选	0,49	0.01	
齊 銅	Cu (88), Sn (12)	宝 塩	0.13 ~ 0.18	0,5	
炭柔酮	C(L22), Mn(0.35)。恐 Pe	20	0,196		
ニクロム	Ni(80), Cr(20)	20	1.0	4	
白食ロジワム	Pt(90), Rh(10)	20	0.22	1,4	
ハスチロイC	Mo(17), Cr(18), Pe(8), W(4), 政Ni	25	1.30	· <10~1	
ハステロイ N	Mo(17), Cr(7), Fd(5), 数N!	24	1.39	1=4	
パーマロイ	Fe(54.7), Ni(45), Mn(0.8)	20	0.45		
	Fe(21.2), N((78.5), Mn(0.3)	20	0.16		
マンガキン	Cu(84), Mn(12), NI(4)	20	0.44	0.010	
원고 <b>∽金</b> 企	Pe(18), NI(75), Cr(2), Cu(5)	20	0,62	~~~ <b>~</b>	
リン党師	Sn(6.08), P(0.01), 烈 Cu	20	0,078		

## 表 14,11 種々の解核化会物の結晶強と健気抵抗率

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	And and in the analysis for full last on the Bull and other Andrew Andre						~ CD-KOM		
	化合物	部晶物理	透热率 ρ 10 <sup>-1</sup> Ω m	<b>25.</b> 0€		化合物	精晶棉造	抵抗率 p 10 <sup>-1</sup> Q m	温 度 #/'C
ホウ化物	CrB <sub>t</sub>	六方(C 32)	21	重濕	酸化物	Cr <sub>6</sub> O <sub>6</sub>	遊雨	1,3×10 <sup>4</sup>	360
	MoB	正方(α)	45	n		HfO <sub>s</sub>	<b>华</b> 斜	8×1019	450
	<i>"</i>	正河(8)	25	, ,	ļ	MgO	立方(B1)	B×10 <sup>14</sup>	850
	NPB	乡对	6.45	n		SIO	六カ	1×1041	20
	TiB,	大方(C 32)	28.4	, ,	-	TIO:	正方	1.2×1016	800
	MgB,	n	115	n		ZrO <sub>2</sub>	1/4 20F	1×1012	385
炭化物	B <sub>4</sub> C	<b>オガ</b>	0.8	意溫	ケイ化物	MoSi,	正方(C11)	21,5	查媽
	MeC	n	97			NoSi.	화方 CrSig 로디	6.8	"
	NЬC	立方(B1)	74	"		TiSi,	n	128	11
	S(C(p)	立方	107	n l		VSI.	n	9.5	n
	TIC	B1	180	n		ZrRuSi	大方(C22)	420	0
	WC	大方	80	"		ZrRhSi	件方(C 23)	250	n
	ZrC	立方(B1)	70	"	リン化物	NIP	件 方	300	0
盤化物	NbN	立方(B1)	200	1000		SiP.	立方(C2)	30	宝温
	Ta,N	大 方	135	,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,		MoaP	正方	140	0
	Tin	立方(B1)	21,7	"		ŹrRuP	大方(C22)	3300	,
	VN	H	200	"		NbPS	科方	3000	'n
	ZrN	η	18.6	1		LaRu,Pie	立方	680	"
跌化物	A1,0,	麗 園	1×10 <sup>24</sup>	14	硫化物	TIS	大方(B 8)	400	五組
	BeQ	<b>*</b> *	4×10 <sup>14</sup>	600		CuS <sub>e</sub>	立方(C2)	150	<u></u>
	CeO <sub>2</sub>	立方	6,6×1010	800	{	CuV <sub>8</sub> S <sub>4</sub>	立方	600	ı,

顧品機造の配号については、極山度一、横山野子、"典立全費 15、横遠無機化学 17、典立出版 (1985),p. 247 参照。 [R.C. Wezst, "Handbook of Chemistry and Physics" CRC (1980)]

族 14.12 金属伝導および金属-半導体転移を示す酸化物の電気盤抗率

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The same of the sa									→ CD-NOM
化食物	和流	<b>抵抗率*1</b> e Q m	<u>T</u>	布移温度 Tra/K	化合物	結品 裕進	極抗率*1 p Q m	T K	版學基度 Tra/K
CrOs Fe,O,	正方立方	2.5×10 <sup>-6</sup> 4×10 <sup>-6</sup> (M) 4×10 <sup>-8</sup> (M)	800 180 110	120	OáO <sub>s</sub>	正为	8×10 <sup>-7</sup> 3.2×10 <sup>-3</sup>	800	
irO <sub>i</sub>	正方	4.9×10 <sup>-7</sup>	800		PtO <sub>1</sub> ReO <sub>2</sub> (β)	内内に	8×10 <sup>-1</sup> 3×10 <sup>-1</sup> 1.0×10 <sup>-4</sup>	300 4.2 300	
MnO <sub>1</sub> MoO <sub>1</sub>	正方	1,1×10 <sup>-4</sup> 8,8×10 <sup>-7</sup>	900 800		ReO,	立方	1.2×10 <sup>-7</sup> 1.8×10 <sup>-7</sup>	4.2 800	
NPO'	立方 正方 "	2×10 <sup>-1</sup> 2×10 <sup>-1</sup> (M) 2×10 <sup>-1</sup> (I)	300 1130 1120	1125	RhO <sub>1</sub> RuO <sub>1</sub>	正方正方	8.5×10 <sup>-7</sup> 2.2×10 <sup>-9</sup>	800 800 4.2	

